

# AN6346N

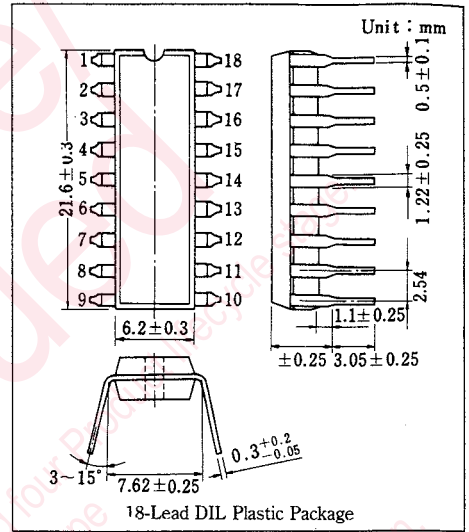
## VTR Cylinder Interface Circuit

### ■ Outline

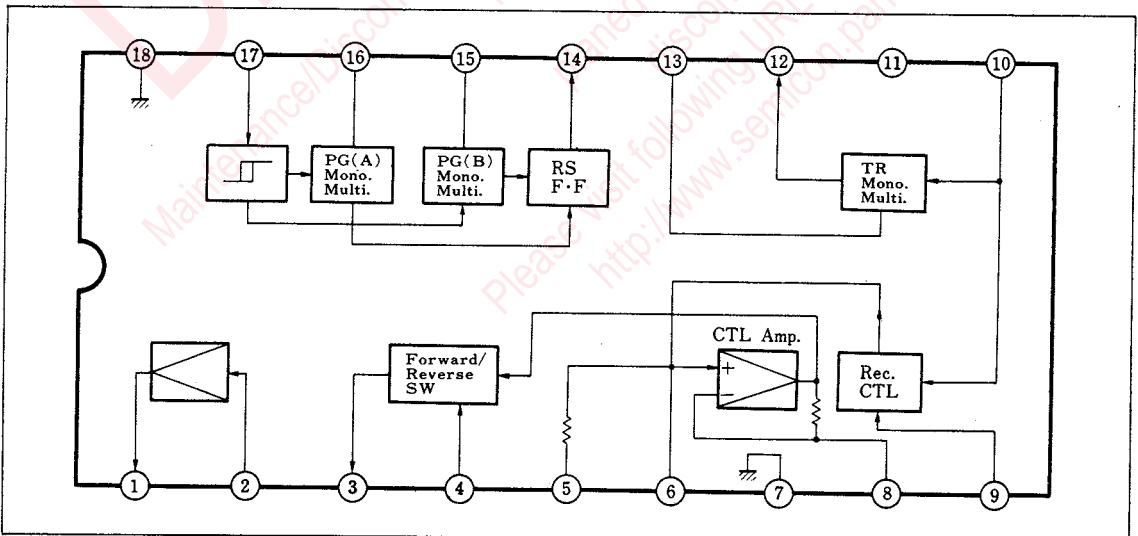
The AN6346N is an integrated circuit designed for VTR cylinder interface.

### ■ Features

- The functions consist of:  
 PG monostable multivibrator  
 Tracking monostable multivibrator  
 CTL amplifier
- Supply voltage: 5V



### ■ Block Diagram



■ Pin

Pin No.	Pin Name	Pin No.	Pin Name
1	P.B. CTL Output	10	1/2 V <sub>ss</sub> Input
2	P.B. CTL Clamp Input	11	V <sub>cc</sub>
3	P.B. CTL Amp. Output	12	Tracking Mono. Multi. Output
4	Forward/Reverse Select	13	Tracking Mono. Multi. Control
5	1/2 V <sub>cc</sub>	14	Head Switch Output
6	CTL Signal	15	PG (B) Mono. Multi.
		16	PG (A) Mono. Multi.
7	GND	17	Cylinder PG Input
8	CTL Amp. Feedback	18	GND
9	Rec./P.B. Select	—	—

■ Absolute Maximum Ratings (Ta=25°C)

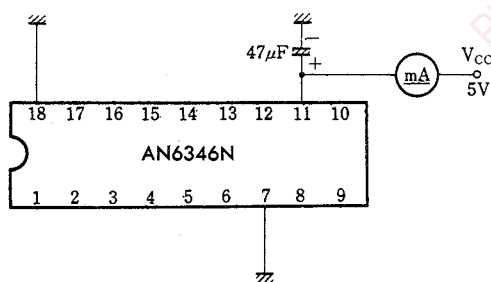
Item	Symbol	Rating	Unit
Supply voltage	V <sub>cc</sub>	6	V
Power dissipation (Ta=70°C)	P <sub>D</sub>	100	mW
Operating ambient temperature	T <sub>opr</sub>	-20~+70	°C
Storage temperature	T <sub>stg</sub>	-40~+150	°C

■ Electrical Characteristics (V<sub>cc</sub>= 5 V, Ta=25°C ± 2 °C)

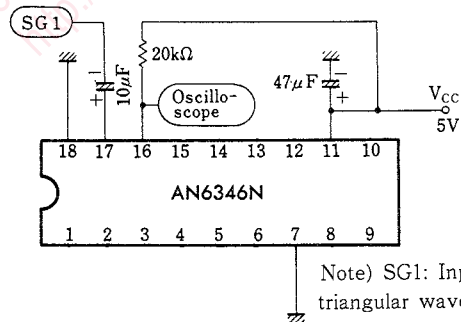
Item	Symbol	Test Circuit	Condition	min.	typ.	max.	Unit
Circuit current	I <sub>11</sub>	1	Without load	7.0		14	mA
PG amp. input sensitivity	S <sub>17</sub>	2		±65			mV
PG A mono. multi. delay amount	T <sub>16</sub>	3	C=0.056 μF, R=20kΩ	690		860	μs
PG B mono. multi. delay amount	T <sub>15</sub>	3	C=0.056 μF, R=20kΩ	690		860	μs
H/SW high-level output	V <sub>OH14</sub>	4	Without load	4.6			V
H/SW low-level input	V <sub>OL14</sub>	4	Without load			0.4	V
1/2 V <sub>ss</sub> input sensitivity	S <sub>10</sub>	5				1.5	V
Rec. start select sensitivity	S <sub>9</sub>	6		3.0			V
For/Rev. select sensitivity	S <sub>4</sub>	7		3.0			V
Rec. CTL high-level output	V <sub>OH6</sub>	8	Without load	4.0			V
Rec. CTL low-level output	V <sub>OL6</sub>	8	Without load			0.4	V
P.B. CTL amp. gain (For.)	G <sub>F3</sub>	9	Without load	60		72	dB
P.B. CTL amp. gain (Rev.)	G <sub>R3</sub>	9		59		72	dB
Tracking mono. multi. delay amount	T <sub>13</sub>	10	C=0.27 μF, R=100kΩ	18		22	ms
P.B. CTL wave shaping input sensitivity	S <sub>2</sub>	11		300			mV

Note) Operating supply voltage range V<sub>cc(oper)</sub>4.5~5.5V

Test Circuit 1 (I<sub>11</sub>)

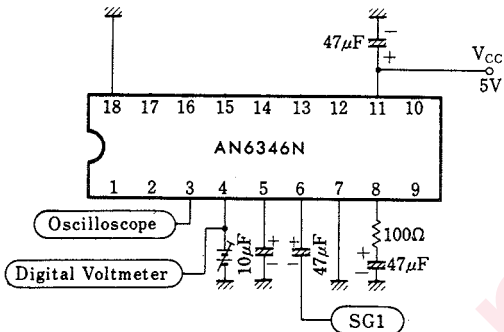


Test Circuit 2 (S<sub>17</sub>)



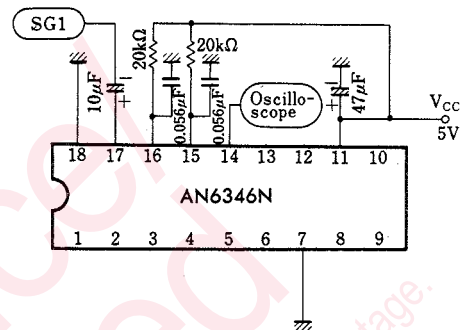
Note) SG1: Input signal triangular wave, f=100Hz

Test Circuit 3 ( $T_{16}$ ,  $T_{15}$ )



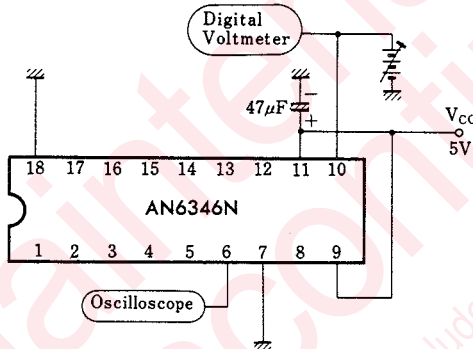
Note) SG1: Input signal sine wave  $f=1\text{kHz}$ ,  $0.2\text{mVp-p}$

Test Circuit 4 ( $V_{OH14}$ ,  $V_{OL14}$ )



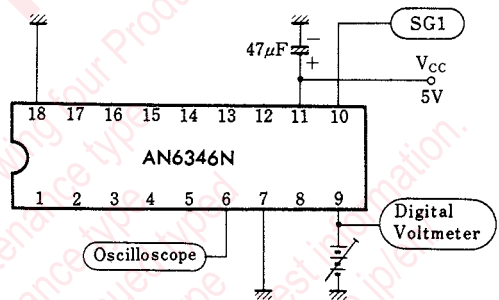
Note) SG1: Input signal triangular wave,  $f=100\text{Hz}$ ,  $1\text{Vp-p}$

Test Circuit 5 ( $S_{10}$ )



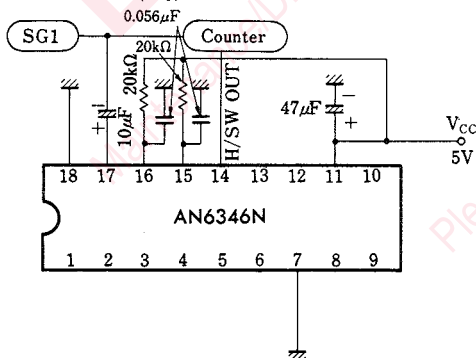
Note) Measure the Pin⑩ voltage at which Pin⑥ output changes after IC internal R-S FF setting (applying pulses to the Pin⑩ in the circuit above).

Test Circuit 6 ( $S_9$ )



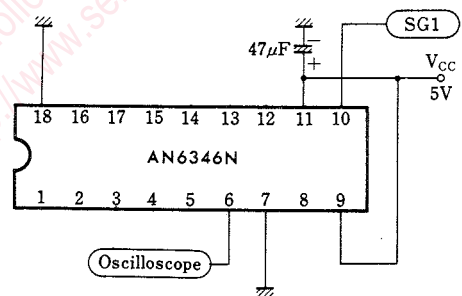
Note) SG1: Input signal rectangular wave,  $f=30\text{Hz}$ ,  $5\text{Vo-p}$ . Measure the Pin⑨ voltage at which no output is made to the Pin⑥.

Test Circuit 7 ( $S_4$ )



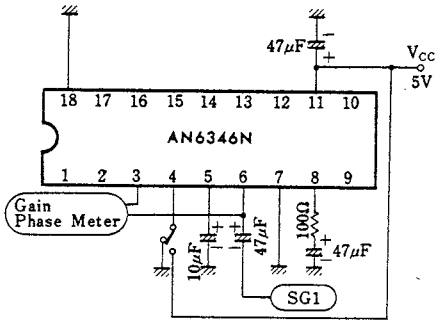
Note) SG1: Input signal rectangular wave,  $f=100\text{Hz}$ ,  $1\text{Vp-p}$ .  $T_{15}$  is a time from a fall of SG1 input signal to a rise of H/SW.OUT.  $T_{16}$  is a time from a rise of SG1 input signal to a fall of H/SW OUT.

Test Circuit 8 ( $V_{OH6}$ ,  $V_{OL6}$ )



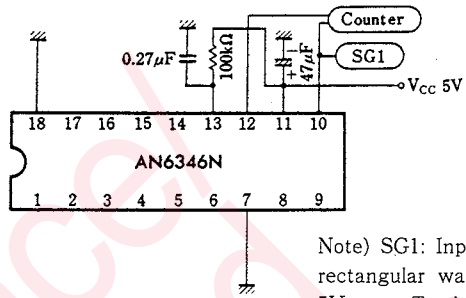
Note) SG1: Input signal rectangular wave,  $f=30\text{Hz}$ ,  $5\text{Vo-p}$

Test Circuit 9 ( $G_{F3}$ ,  $G_{R3}$ )



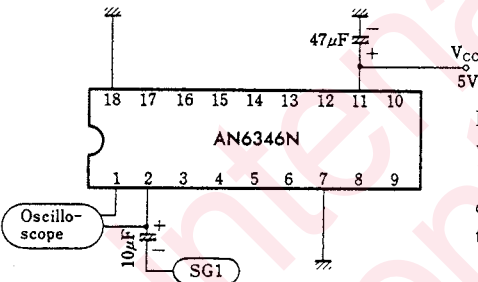
Note) SG1: Input signal sine wave,  $f=1\text{kHz}$ ,  $0.2\text{mVp-p}$ .  $G_{F3}$  for Pin④ GND,  $G_{R3}$  for Pin④  $V_{cc}$

Test Circuit 10 ( $T_{13}$ )



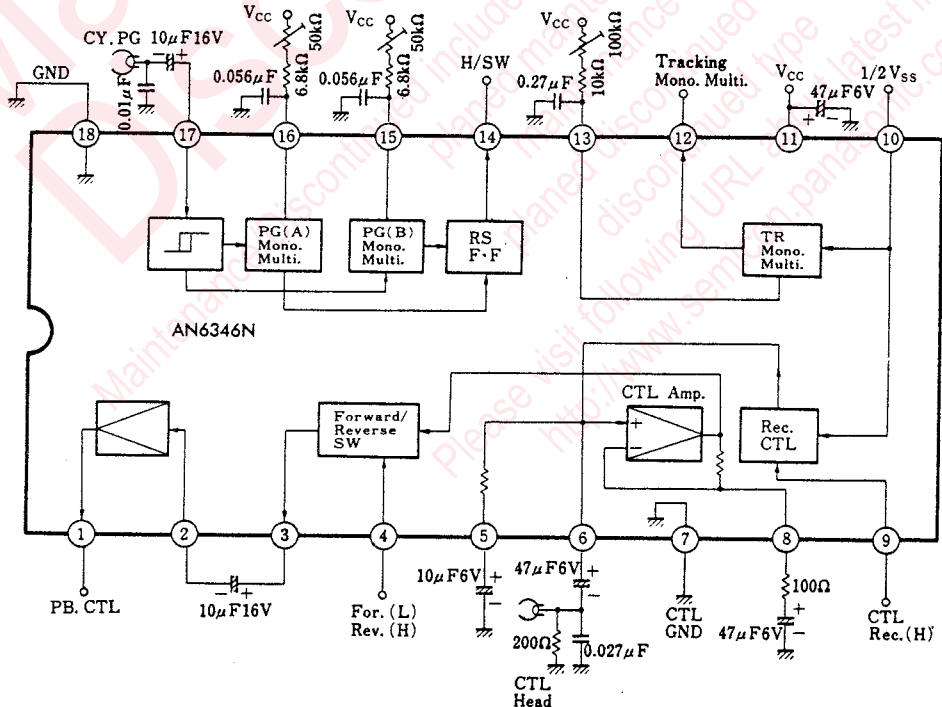
Note) SG1: Input signal rectangular wave,  $f=30\text{Hz}$ ,  $5V_o-p$ .  $T_{13}$  is a time from a rise of SG1 to a fall of Pin⑩ output.

Test Circuit 11 ( $S_2$ )



Note) SG1: Input signal rectangular wave,  $f=30\text{Hz}$ .  $V_H-V_L$  of SG1= $S_2$  when an SG1 signal level is changed and a signal is issued to the Pin①

Application Circuit



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